

High Performance Laser Diode Series

Blue 445nm CoS Package

KLCB0200Y2WW

■ Overview

Nuvoton Technology Corporation Japan provides a series of blue laser diode. The laser diode which emits 445nm laser light, is assembled as Chip on Submount, CoS package. Unique compound semiconductor process technology and low optical loss structure can realize high output power and high reliability lasers which are suitable for industrial use.

Features

Wavelength: 445 nm (typ.)

●High Output Power, Multiple Transverse Mode

●Emitter Size: 45um x 1um

●Operating Temperature (0 to +60 degrees C)

●Chip on Submount (CoS) Package

Applications

Material Processing

Bio Medical

Display

Other Industrial Use

■ Absolute Maximum Ratings

Outline image							
p-electrode							
Length x Width x Height 4.0 x 3.0 x 0.58 mm							

Item	Symbol	Value	Unit	Condition
Operating current	lop	3.5	Α	CW
Reverse voltage	Vr	5.0	V	-
Operating temperature (Case)	Tc	0 to +60	°C	-
Storage temperature	Tstg	-40 to +85	°C	-

■ Electrical and Optical Characteristics

Tc=25°C, pulse

	Item	Symbol	Min.	Тур.	Max.	Unit	Condition
Threshold current		lth	-	0.35	0.50	Α	pulse
Optical	output power	Po	4.5	5.0	-	W	lop=3.2A
Opera	ting voltage	Vop	-	4.6	5.5	V	lop=3.2A
Slope	efficiency	Se	1.5	1.8	2.0	W/A	lop=0.5A ~ 3.2A
Peak wavelength		λ	438	445	452	nm	lop=3.2A
Beam divergence	Parallel 1)	θh	6	9	14	deg.	lop=3.2A
	Perpendicular 1)	θν	40	45	50	deg.	lop=3.2A

Note) 1) Full width at 1/e² of the peak intensity.

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